TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74LCX273F, TC74LCX273FK

Low-Voltage Octal D-Type Flip-Flop with Clear with 5-V Tolerant Inputs and Outputs

The TC74LCX273 is a high-performance CMOS octal D-type flip-flop. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low-power dissipation.

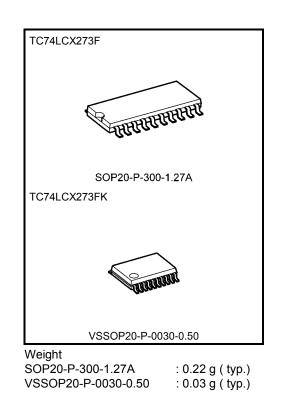
The device is designed for low-voltage  $(3.3 \text{ V}) \text{ V}_{CC}$  applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 8 bit D-type flip-flop is controlled by a clock input (CK) and a clear input ( $\overline{\text{CLR}}$ ). When the  $\overline{\text{CLR}}$  input is low, the eight outputs are at a low logic level.

All inputs are equipped with protection circuits against static discharge.

#### Features

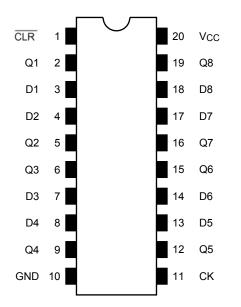
- Low-voltage operation:  $V_{CC}$  = 1.65 to 3.6 V
- High-speed operation:  $t_{pd} = 8.5 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: |IOH|/IOL = 24 mA (min) (VCC = 3.0 V)
- Latch-up performance:  $>\pm 500$  mA
- Available in JEITA SOP, VSSOP (US)
- Power-down protection is provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 273 type



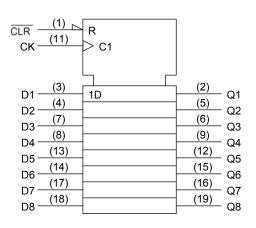
Note: The Electrical Characteristics of  $V_{CC}$  = 1.8 ± 0.15 V is only applicable for products which manufactured from January 2009 onward.

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## Pin Assignment (top view)



#### **IEC Logic Symbol**

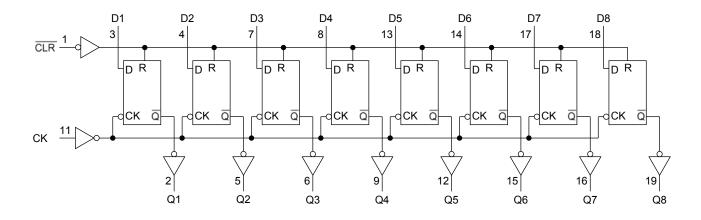


#### Truth Table

	Inputs	Outputs	Function	
CLR	D	СК	СК Q	
L	Х	Х	L	Clear
Н	L		L	_
Н	Н		Н	_
Н	Х		Qn	No change

X: Don't care

#### System Diagram



#### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5 to 7.0	V
DC input voltage	VIN	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	Vout	-0.5 to V <sub>CC</sub> + 0.5	V
		(Note 3)	
Input diode current	Iк	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V <sub>CC</sub> /ground current	ICC/IGND	±100	mA
Storage temperature	T <sub>stg</sub>	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: VCC = 0 V

- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: VOUT < GND, VOUT > VCC

#### **Operating Ranges (Note 1)**

Characteristics	Symbol	Rating	Unit	
Deviewenterettere	Maa	1.65 to 3.6		
Power supply voltage	Vcc	1.5 to 3.6 (Note 2)	V	
Input voltage	VIN	0 to 5.5	V	
	Vour	0 to 5.5 (Note 3)	V	
Output voltage	Vout	0 to V <sub>CC</sub> (Note 4)	v	
Output current	IOH/IOL	±24 (Note 5)	m (	
Output current	IOH/IOL	±12 (Note 6)	mA	
Operating temperature	Topr	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V<sub>CC</sub> or GND.

Note 2: Data retention only

Note 3: VCC = 0 V

Note 4: High or low state

Note 5:  $V_{CC} = 3.0$  to 3.6 V

Note 6: VCC = 2.7 to 3.0 V

Note 7: VIN = 0.8 to 2.0 V, VCC = 3.0 V

#### **Electrical Characteristics**

#### DC Characteristics (Ta = -40 to $85^{\circ}$ C)

Charac	Characteristics Symbol Test Condition		Min	Max	Unit			
		0,11201		Vcc (V)				••••
					1.65 to 2.3	V <sub>CC</sub> × 0.9		
	H-level	VIH			2.3 to 2.7	1.7	_	
					2.7 to 3.6	2.0		V
Input voltage					1.65 to 2.3		Vcc × 0.1	V
	L-level	VIL			2.3 to 2.7		0.7	
					2.7 to 3.6		0.8	
				Іон = –100 μА	1.65 to 3.6	Vcc-0.2		
				I <sub>OH</sub> = –4 mA	1.65	1.05		
	H-level		$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = –8 mA	2.3	1.7		
	H-level	V <sub>OH</sub>		I <sub>OH</sub> = –12 mA	2.7	2.2	_	
				I <sub>OH</sub> = –18 mA	3.0	2.4	_	
				I <sub>OH</sub> = –24 mA	3.0	2.2		
Output voltage				I <sub>OL</sub> = 100 μA	1.65 to 3.6		0.2	
				I <sub>OL</sub> = 4 mA	1.65		0.45	
			., ., .,	I <sub>OL</sub> = 8 mA	2.3		0.7	
	L-level	V <sub>OL</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 12 mA	2.7		0.4	
				I <sub>OL</sub> = 16 mA	3.0		0.4	
				I <sub>OL</sub> = 24 mA	3.0		0.55	
Input leakage cur	rent	l <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		1.65 to 3.6		±5.0	μA
Power-off leakage	e current	IOFF	IOFF VIN/VOUT = 5.5 V		0		10.0	μA
Quieseert sure h	ourrant	le -	VIN = VCC or GND		1.65 to 3.6		10.0	
Quiescent supply	current	Icc	V <sub>IN</sub> = 3.6 to 5.5 V	1	1.65 to 3.6		±10.0	μA
Increase in ICC pe	er input	ΔICC	VIN = VCC - 0.6	V (per 1 input)	2.7 to 3.6		500	



AC Characteristics (Ta = -40 to  $85^{\circ}$ C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
			$1.8\pm0.15$	50	_	
	fMAX		$\textbf{2.5}\pm\textbf{0.2}$	100	_	MHz
Maximum clock frequency		(Figure 1, Figure 2)	2.7	150	_	
			$\textbf{3.3}\pm\textbf{0.3}$	150	_	
			$1.8\pm0.15$	_	30.0	
	tPLH		$2.5\pm0.2$		10.5	
Propagation delay time (CK-Q)	tPHL	(Figure 1, Figure 2)	2.7	_	9.5	ns
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	
			$1.8\pm0.15$		30.0	
			$2.5\pm0.2$		10.5	
Propagation delay time ( CLR -Q)	<b>t</b> PHL	(Figure 1, Figure 3)	2.7		9.5	ns
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	
			$1.8\pm0.15$	10.0		ns
	tw (H)		$2.5\pm0.2$	5.0		
Minimum pulse width (CK)	tw (L)	(Figure 1, Figure 2)	2.7	3.3	_	
			$\textbf{3.3}\pm\textbf{0.3}$	3.3		
			$1.8\pm0.15$	10.0	_	ns
$\mathbf{M}$			$\textbf{2.5}\pm\textbf{0.2}$	5.0		
Minimum pulse width ( $\overline{CLR}$ )	t <sub>w (L)</sub>	(Figure 3)	2.7	3.3	_	
			$\textbf{3.3}\pm\textbf{0.3}$	3.3		
			$1.8\pm0.15$	10.0		
			$\textbf{2.5}\pm\textbf{0.2}$	5.0	_	
Minimum setup time	ts	(Figure 1, Figure 2)	2.7	2.5		ns
			$\textbf{3.3}\pm\textbf{0.3}$	2.5		
			$1.8\pm0.15$	1.5		
Minimum hald time		(Figure 1 Figure 2)	$2.5\pm0.2$	1.5	_	ns
Minimum hold time	th	(Figure 1, Figure 2)	2.7	1.5		
			$\textbf{3.3}\pm\textbf{0.3}$	1.5		
			$1.8\pm0.15$	8.0	_	
Minimum removal time		(Figure 4)	$2.5\pm0.2$	4.0		ns
winimum removal time	t <sub>rem</sub>	(Figure 4)	2.7	2.5	_	
			$\textbf{3.3}\pm\textbf{0.3}$	2.0		
	t <sub>osLH</sub>	A1-1-\	2.7	_	_	
Output to output skew	t <sub>osHL</sub>	(Note)	$\textbf{3.3}\pm\textbf{0.3}$	_	1.0	ns

Note: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

#### **Dynamic Switching Characteristics**

#### $(Ta = 25^{\circ}C, input: tr = tf = 2.5 ns, CL = 50 pF, RL = 500 \Omega)$

Characteristics	Symbol	Test Condition	Vcc (V)	Тур.	Unit
Quiet output maximum dynamic $V_{OL}$	VOLP	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic $V_{OL}$	V <sub>OLV</sub>	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

#### Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Vcc (V)	Тур.	Unit
Input capacitance	CIN		3.3	7	pF
Output capacitance	COUT		0	8	pF
Power dissipation capacitance	CPD	$f_{IN} = 10 \text{ MHz}$ (Note)	3.3	25	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $ICC (opr) = CPD \cdot VCC \cdot fIN + ICC/8 (per bit)$ 

#### **AC Test Circuit**

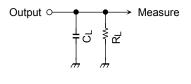


Figure 1

#### **AC Waveform**

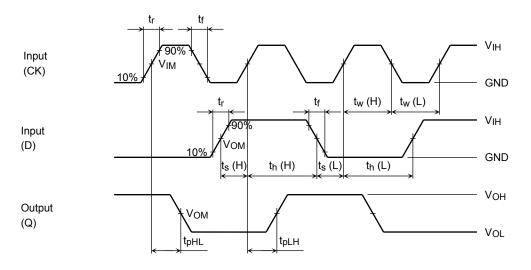


Figure 2  $t_{pLH}, t_{pHL}, t_w, t_s, t_h$ 



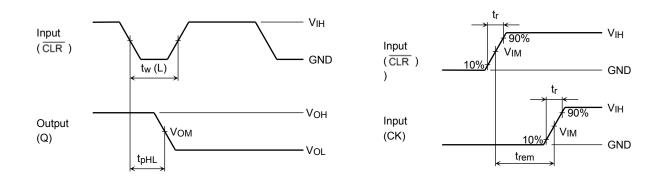
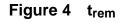


Figure 3 t<sub>pHL</sub>



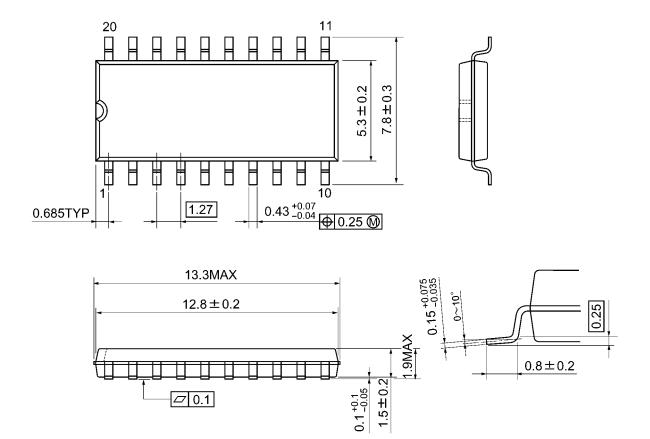
		Vcc						
	Symbol	3.3 ± 0.3 V 2.7 V	$2.5\pm0.2~V$	$1.8\pm0.15~V$				
Input	VIH	2.7 V	V <sub>CC</sub>	Vcc				
	VIM	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2				
	t <sub>r</sub> , t <sub>f</sub>	2.5 ns	2.0 ns	2.0 ns				
Output	Vom	1.5 V	V <sub>OH</sub> /2	V <sub>OH</sub> /2				
Load	CL	50 pF	30 pF	30 pF				
	RL	500 Ω	500 Ω	1 kΩ				



#### **Package Dimensions**

SOP20-P-300-1.27A

Unit: mm



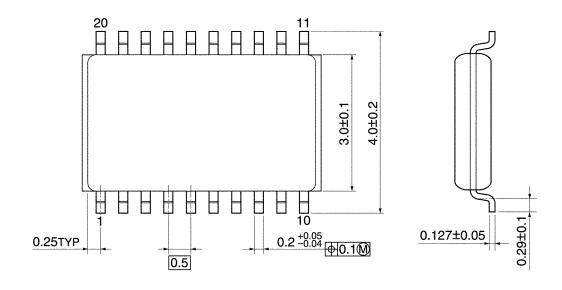
Weight: 0.22 g (typ.)

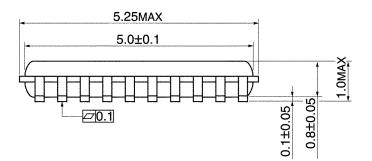


#### **Package Dimensions**

VSSOP20-P-0030-0.50

Unit: mm





Weight: 0.03 g (typ.)

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